

# SEMICONDUCTOR TECHNICAL DATA

# SMAB36

## SCHOTTKY BARRIER TYPE DIODE

## SWITCHING TYPE POWER SUPPLY APPLICATIONS.

#### **FEATURES**

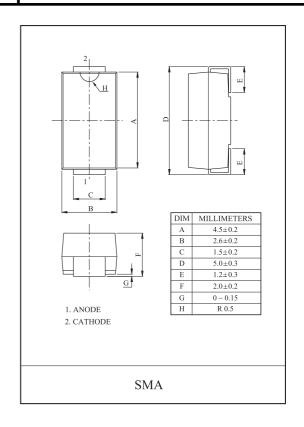
- · Low Profile Surface Mount Package.
- · Low Power Loss, High Efficiency.
- · For Use in Low Voltage, High Frequency inverters, Free Wheeling, and Polarity Protection Applications.

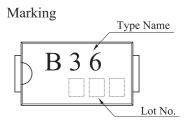
#### **APPLICATION**

- · Switching Power Supply.
- · DC/DC Converter.
- · Home Appliances, Office Equipment.
- · Telecommunication.

#### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	60	V
Average Output Rectitifed Current	I <sub>O</sub> 3		A
Peak One Cycle Surge Forward Current (Non-Repetitive 60Hz)	$I_{FSM}$	70	A
Junction Temperature	T <sub>j</sub>	-40 ~150	$^{\circ}$
Storage Temperature Range	$T_{stg}$	-40 ~150	°C





# ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	$V_{FM}$	I <sub>FM</sub> =3.0A	-	-	0.6	V
Repetitive Peak Reverse Current	$I_{RRM}$	V <sub>RRM</sub> =Rated	-	-	0.2	mA
Thermal Resistance	$R_{th(j-1)}$	Junction to lead	-	-	23	
	R <sub>th(j-a)</sub>	Junction to ambient	_	_	108	°C/W
		(on alumina substrate)				

